

MSC1175M Information


For Reference Only

Part Number [MSC1175M](#)
Manufacturer Microsemi Corporation
Category Discrete Semiconductor Products
[Transistors - Bipolar \(BJT\) - RF](#)
Description TRANS RF BIPO 400W 12A M218
Package M218
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com



[Request a Quote](#)

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


MSC1175M Specifications

Manufacturer Part Number	MSC1175M
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF
Package	M218
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	65V
Frequency - Transition	1.025GHz ~ 1.15GHz
Noise Figure (dB Typ @ f)	-
Gain	8dB
Power - Max	400W
DC Current Gain (hFE) (Min) @ Ic, Vce	15 @ 1A, 5V
Current - Collector (Ic) (Max)	12A
Operating Temperature	250°C (TJ)
Mounting Type	Chassis Mount
Package / Case	M218
Supplier Device Package	M218

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MSC1175M Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MSC1175M Payment Methods



MSC1175M Shipping Methods



If you have any question about MSC1175M, please do not hesitate to contact us!

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